

SKiiP 28ANB16V1



MiniSKiiP[®] 2

3-phase bridge rectifier + brake chopper

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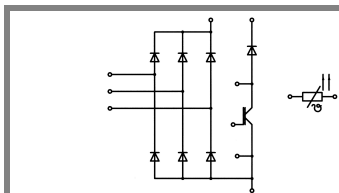
Target Data

Features

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications

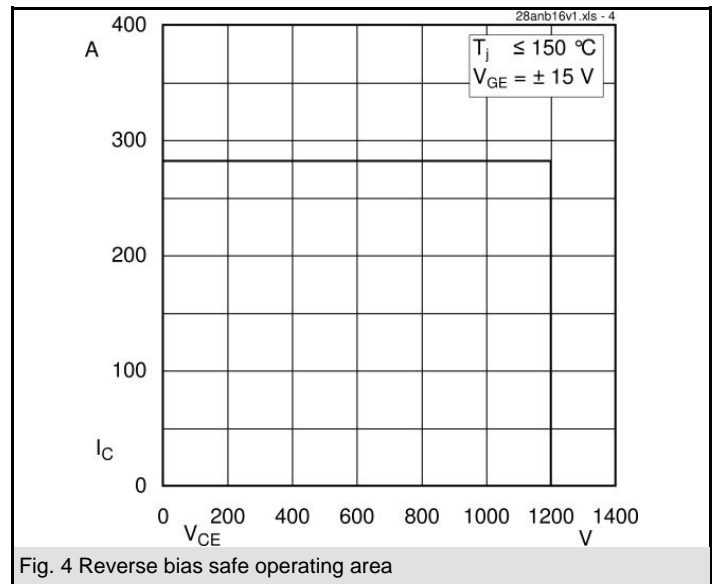
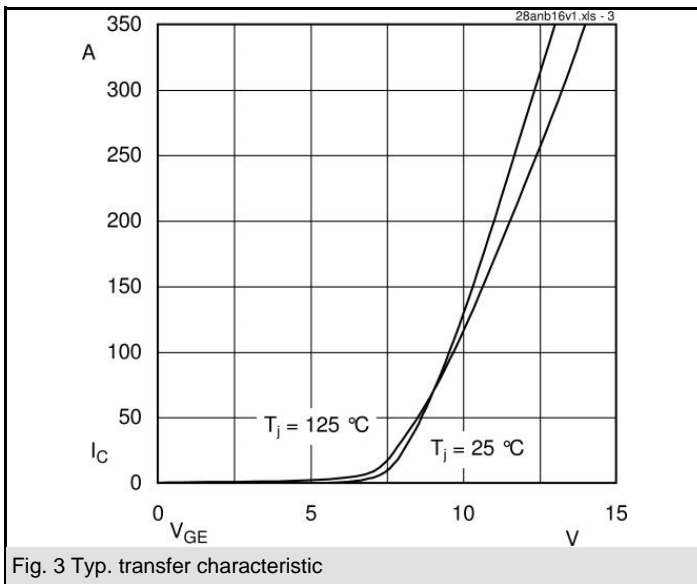
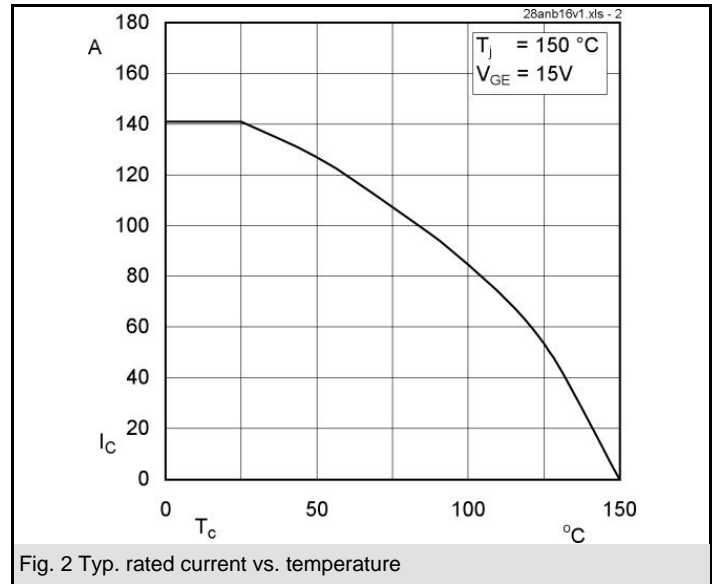
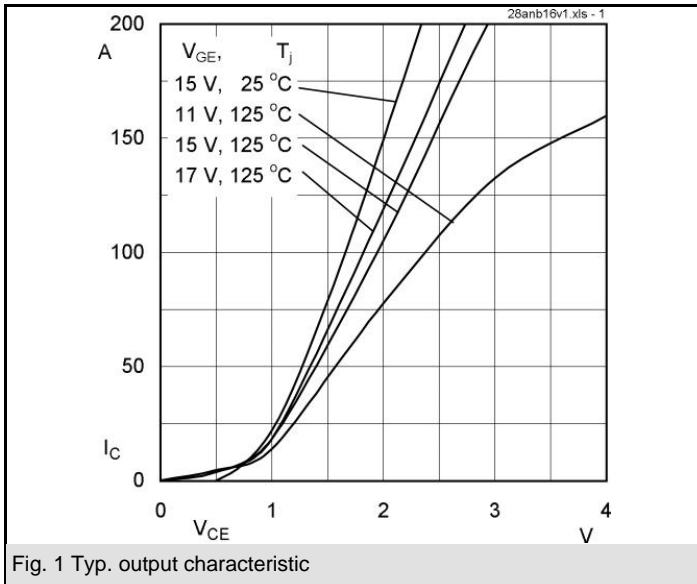
- Input bridge for Inverter up to 39 kVA



ANB

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Chopper			
V_{CES}		1200	V
I_C	$T_s = 25\text{ (70) °C}$	141 (107)	A
I_{CRM}	$T_s = 25\text{ (70) °C}$, $t_p \leq 1\text{ ms}$	282 (214)	A
V_{GES}		± 20	V
T_j		- 40 ... + 150	°C
Diode - Chopper			
I_F	$T_s = 25\text{ (70) °C}$	118 (88)	A
I_{FRM}	$T_s = 25\text{ (70) °C}$, $t_p \leq 1\text{ ms}$	236 (176)	A
T_j		- 40 ... + 150	°C
Diode - Rectifier			
V_{RRM}		1600	V
I_F	$T_s = 70\text{ °C}$	87	A
I_{FSM}	$t_p = 10\text{ ms}$, $\sin 180\text{ °}$, $T_j = 25\text{ °C}$	1150	A
i^2t	$t_p = 10\text{ ms}$, $\sin 180\text{ °}$, $T_j = 25\text{ °C}$	6600	A ² s
T_j		- 40 ... + 150	°C
I_{tRMS}	per power terminal (20 A / spring)	120	A
T_{stg}	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Chopper					
V_{CEsat}	$I_C = 105\text{ A}$, $T_j = 25\text{ (125) °C}$		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 3\text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,9)	1,2 (1,1)	V
r_T	$T_j = 25\text{ (125) °C}$		6,7 (10)	8,6 (12)	mΩ
C_{ies}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		7,1		nF
C_{oes}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		1,5		nF
C_{res}	$V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$		1,3		nF
$R_{th(j-s)}$	per IGBT		0,3		K/W
$t_{d(on)}$	under following conditions		85		ns
t_r	$V_{CC} = 600\text{ V}$, $V_{GE} = \pm 15\text{ V}$		30		ns
$t_{d(off)}$	$I_C = 105\text{ A}$, $T_j = 125\text{ °C}$		430		ns
t_f	$R_{Gon} = R_{Goff} = 5,5\text{ Ω}$		90		ns
E_{on}	inductive load		13,7		mJ
E_{off}			12,8		mJ
Diode - Chopper					
$V_F = V_{EC}$	$I_F = 105\text{ A}$, $T_j = 25\text{ (125) °C}$		1,6 (1,6)	1,8 (1,8)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,8)	1,1 (0,9)	V
r_T	$T_j = 25\text{ (125) °C}$		5,7 (7,6)	6,7 (8,6)	mΩ
$R_{th(j-s)}$	per diode		0,55		K/W
I_{RRM}	under following conditions		146		A
Q_{rr}	$I_F = 105\text{ A}$, $V_R = 600\text{ V}$		24		μC
E_{rr}	$V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$		9,7		mJ
	$di_F/dt = 3990\text{ A/μs}$				
Diode - Rectifier					
V_F	$I_F = 75\text{ A}$, $T_j = 25\text{ °C}$		1,2		V
$V_{(TO)}$	$T_j = 150\text{ °C}$		0,8		V
r_T	$T_j = 150\text{ °C}$		7		mΩ
$R_{th(j-s)}$	per diode		0,65		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
Mechanical Data					
w			65		g
M_s	Mounting torque	2		2,5	Nm



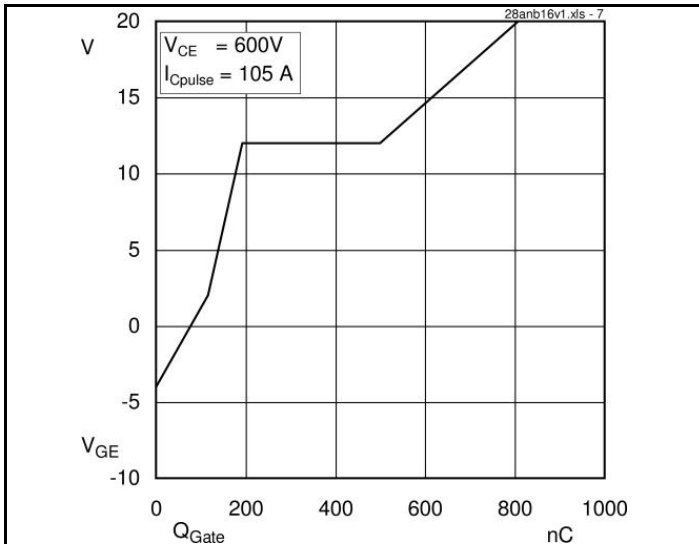


Fig. 7 Typ. gate charge characteristic

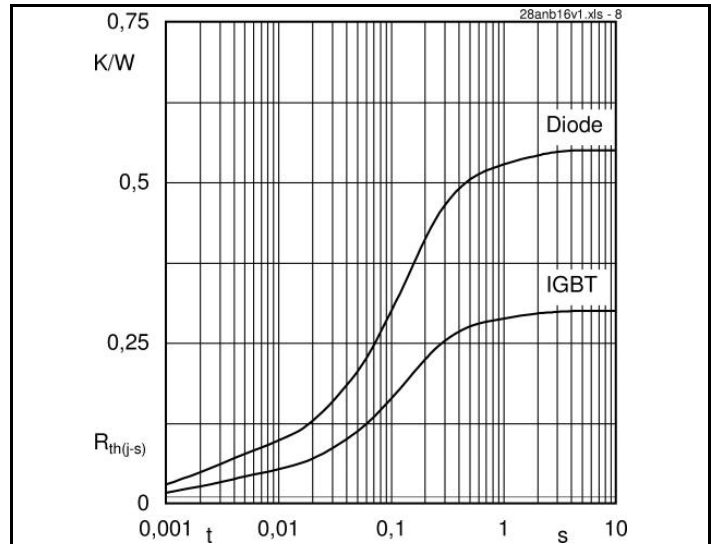


Fig. 8 Typ. thermal impedance

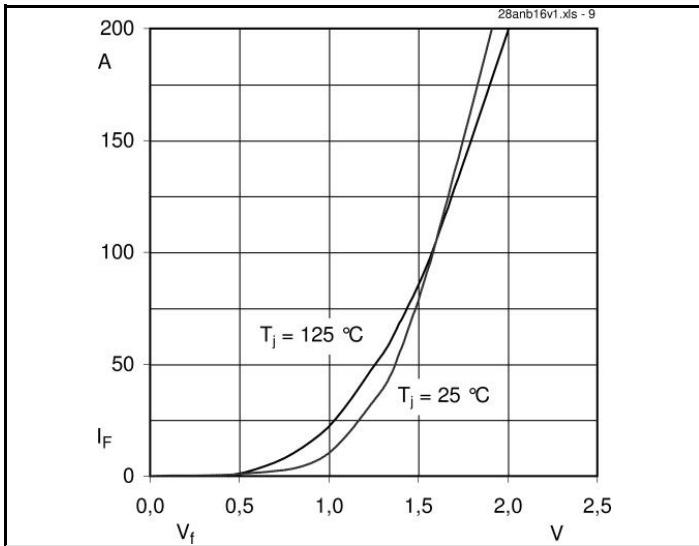


Fig. 9 Typ. freewheeling diode forward characteristic

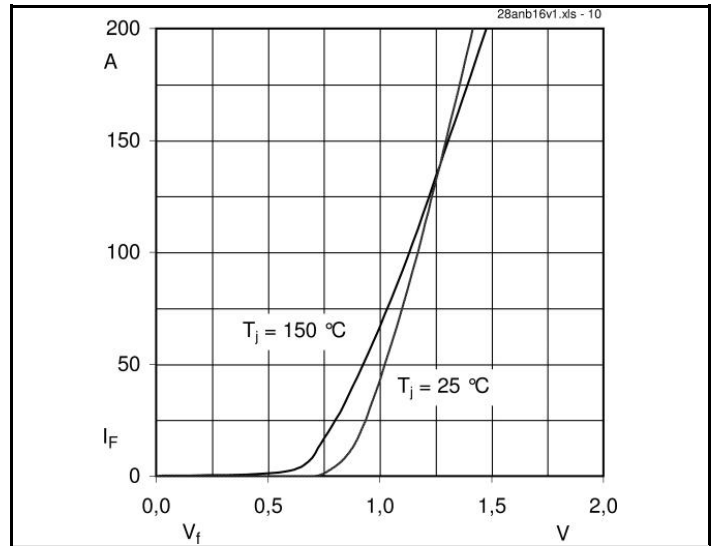


Fig. 10 Typ. input bridge forward characteristic

